Excellent Integrated System Limited

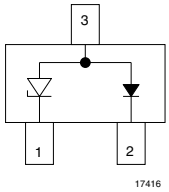
Stocking Distributor

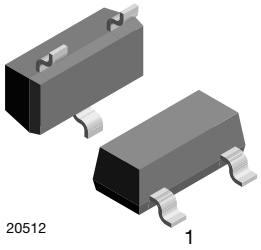
Click to view price, real time Inventory, Delivery & Lifecycle Information:

Vishay Semiconductor/Diodes Division
GL12T-E3-08

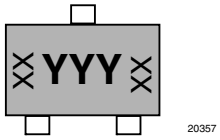
For any questions, you can email us directly:
sales@integrated-circuit.com

Low Capacitance ESD Protection Diodes for High-Speed Data Interfaces





MARKING (example only)



Bar = cathode marking
YYY = type code (see table below)
XX = date code

FEATURES

- IEC 61000-4-5 (lightning) see I_{PPM} below
- ESD-protection acc. IEC 61000-4-2
  ± 8 kV contact discharge
  ± 15 kV air discharge
- ESD capability according to AEC-Q101: human body model: class H3B: > 8 kV
- SOT-23 package
- High temperature soldering guaranteed: 260 °C/10 s at terminals
- Low capacitance for high speed data lines, cellular handsets, USB port protection, LAN equipment, peripherals
- e3 - Sn
- AEC-Q101 qualified available
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free
e3
RoHS COMPLIANT
HALOGEN FREE
GREEN (5-2008)

ORDERING INFORMATION

PART NUMBER (EXAMPLE)	ENVIRONMENTAL AND QUALITY CODE				PACKAGING CODE		ORDERING CODE (EXAMPLE)
	AEC-Q101 QUALIFIED	RoHS-COMPLIANT + LEAD (Pb)-FREE		TIN PLATED	3K PER 7" REEL (8 mm TAPE), 15K/BOX = MOQ	10K PER 13" REEL (8 mm TAPE), 10K/BOX = MOQ	
		STANDARD	GREEN				
GL05T-		E		3	-08		GL05T-E3-08
GL05T-			G	3	-08		GL05T-G3-08
GL05T-	H	E		3	-08		GL05T-HE3-08
GL05T-	H		G	3	-08		GL05T-HG3-08
GL05T-		E		3		-18	GL05T-E3-18
GL05T-			G	3		-18	GL05T-G3-18
GL05T-	H	E		3		-18	GL05T-HE3-18
GL05T-	H		G	3		-18	GL05T-HG3-18

PACKAGE DATA

DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
GL05T	SOT-23	L05	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		L06	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL12T	SOT-23	L12	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		L13	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL15T	SOT-23	L15	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		L16	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
GL24T	SOT-23	L24	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		L25	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS GL05T					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I_{PPM}	25	A
Peak pulse power	8/20 µs waveform		P_{PP}	300	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses		V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses			± 15	kV
Blocking voltage	I_B = 1 µA	Pin 2-1 or pin 2-3	V_B	70	V
Operating temperature	Junction temperature		T_J	-55 to +150	°C
Storage temperature			T_{STG}	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS GL12T					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I_{PPM}	12	A
Peak pulse power	8/20 µs waveform		P_{PP}	300	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses		V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses			± 15	kV
Blocking voltage	I_B = 1 µA	Pin 2-1 or pin 2-3	V_B	70	V
Operating temperature	Junction temperature		T_J	-55 to +150	°C
Storage temperature			T_{STG}	-55 to +150	°C

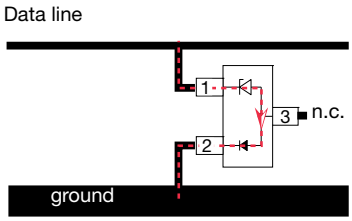
ABSOLUTE MAXIMUM RATINGS GL15T					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I_{PPM}	10	A
Peak pulse power	8/20 µs waveform		P_{PP}	300	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses		V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses			± 15	kV
Blocking voltage	I_B = 1 µA	Pin 2-1 or pin 2-3	V_B	70	V
Operating temperature	Junction temperature		T_J	-55 to +150	°C
Storage temperature			T_{STG}	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS GL24T					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I_{PPM}	5	A
Peak pulse power	8/20 µs waveform		P_{PP}	300	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses		V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses			± 15	kV
Blocking voltage	I_B = 1 µA	Pin 2-1 or pin 2-3	V_B	70	V
Operating temperature	Junction temperature		T_J	-55 to +150	°C
Storage temperature			T_{STG}	-55 to +150	°C

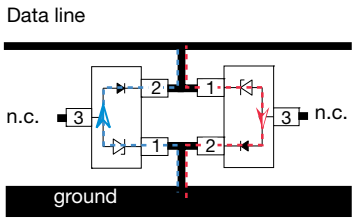
The GLxxT contains an avalanche diode (pin 3-1) and a switching diode (pin 3-2). With pin 1 connected to the signal or data line and pin 2 connected to ground both diodes are in series (pin 3 remains unconnected). The big and robust avalanche diode, driven in reverse direction, provides the working range V_{RWM} of 5 V, 12 V, 15 V or 24 V. Due to its size the capacitance of the avalanche diode is in the range of typ. 260 pF (GL05T) and 65 pF (GL24T). The small switching diode in series has a low capacitance of just 2.5 pF (typ.). As both diodes are in series (with pin 3 not connected) the total capacitance of both diodes measured between pin 1 and 2 is as low as the capacitance of the switching diode.

Before the GLxxT can provide this low capacitance the big capacitance of the avalanche diode has to be charged up with the first signal or data pulses. This is usually no problem for digital signals like USB or other data ports.

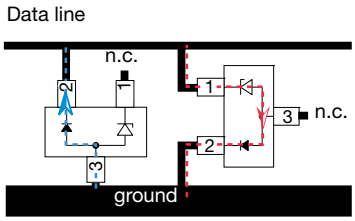
With the GLxxT a signal or data line can be protected against positive transients only. For negative transients another GLxxT can be used to provide a back path for the negative transients as well.



Uni
Unidirectional clamping performance for positive transients only.



BiSy
Bidirectional and **Sy**mmetrical clamping performance for positive and negative transients.



BiAs
Bidirectional and **As**ymmetrical clamping performance for positive and negative transients.

ELECTRICAL CHARACTERISTICS GL05T (T_{amb} = 25 °C unless otherwise specified)
pin 1 to pin 2; pin 3 not connected

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5	V
Reverse voltage	at I_R = 20 µA	V_R	5	-	-	V
Reverse current	at V_R = 5 V	I_R	-	-	20	µA
Reverse breakdown voltage	at I_R = 1 mA	V_{BR}	6.9	7.5	8.0	V
Reverse clamping voltage	at I_{PP} = 1 A	V_C	-	-	9.8	V
	at I_{PP} = 5 A		-	-	11	V
Capacitance	at V_R = 0 V; f = 1 MHz	C_D	-	2.5	5	pF

ELECTRICAL CHARACTERISTICS GL12T (T_{amb} = 25 °C unless otherwise specified)
pin 1 to pin 2; pin 3 not connected

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	12	V
Reverse voltage	at I_R = 1 µA	V_R	12	-	-	V
Reverse current	at V_R = 12 V	I_R	-	-	1	µA
Reverse breakdown voltage	at I_R = 1 mA	V_{BR}	13.3	14.3	17.2	V
Reverse clamping voltage	at I_{PP} = 1 A	V_C	-	-	19	V
	at I_{PP} = 5 A		-	-	24	V
Capacitance	at V_R = 0 V; f = 1 MHz	C_D	-	2.5	5	pF

ELECTRICAL CHARACTERISTICS GL15T (T_{amb} = 25 °C unless otherwise specified)
pin 1 to pin 2; pin 3 not connected

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	15	V
Reverse voltage	at I_R = 1 µA	V_R	15	-	-	V
Reverse current	at V_R = 15 V	I_R	-	-	1	µA
Reverse breakdown voltage	at I_R = 1 mA	V_{BR}	16.7	17.7	22	V
Reverse clamping voltage	at I_{PP} = 1 A	V_C	-	-	24	V
	at I_{PP} = 5 A		-	-	33	V
Capacitance	at V_R = 0 V; f = 1 MHz	C_D	-	2.5	5	pF

ELECTRICAL CHARACTERISTICS GL24T (T_{amb} = 25 °C unless otherwise specified)
pin 1 to pin 2; pin 3 not connected

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	24	V
Reverse voltage	at I_R = 1 µA	V_R	24	-	-	V
Reverse current	at V_R = 24 V	I_R	-	-	1	µA
Reverse breakdown voltage	at I_R = 1 mA	V_{BR}	26.7	28.2	33	V
Reverse clamping voltage	at I_{PP} = 1 A	V_C	-	-	43	V
	at I_{PP} = 5 A		-	-	55	V
Capacitance	at V_R = 0 V; f = 1 MHz	C_D	-	2.5	5	pF

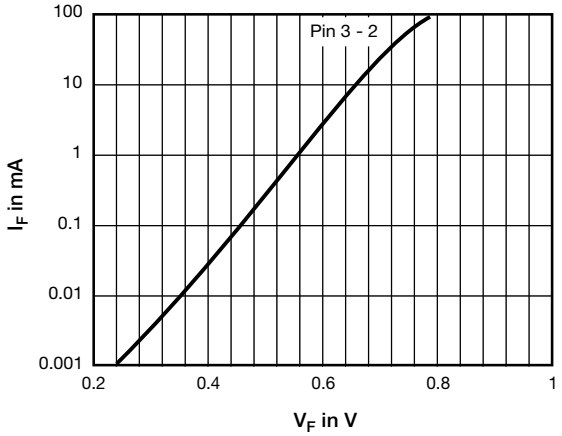


Fig. 1 - Typical Forward Current I_F vs. Forward Voltage V_F

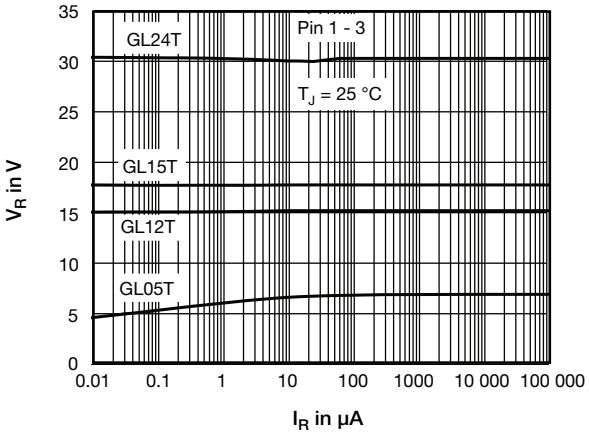


Fig. 3 - Typical Reverse Voltage V_R vs. Reverse Current I_R

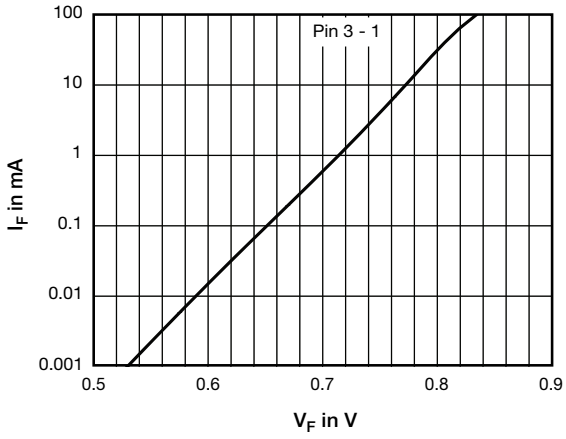
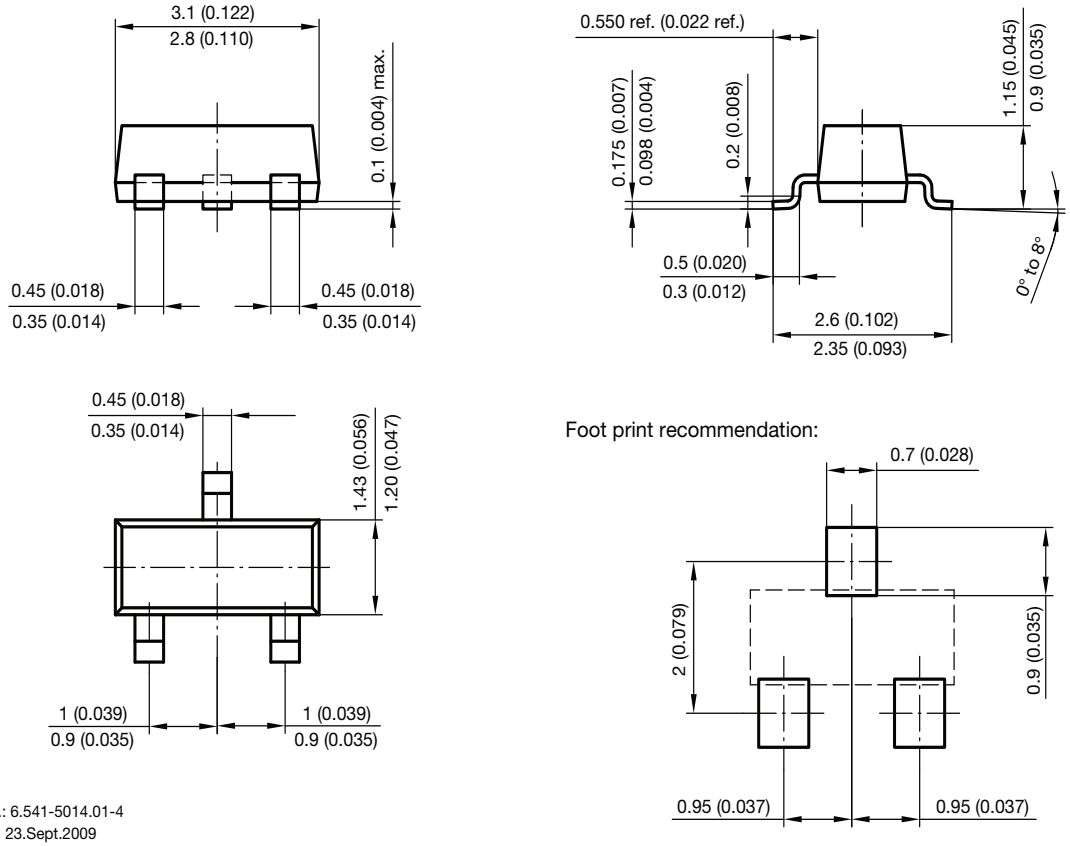
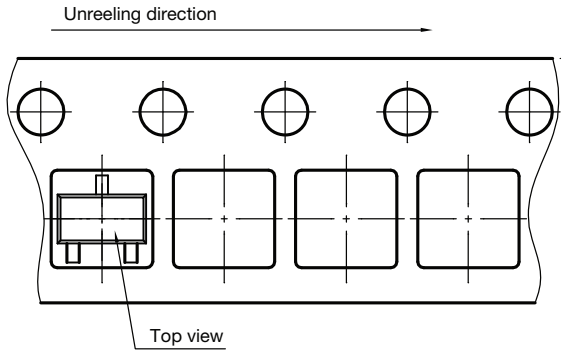


Fig. 2 - Typical Forward Current I_F vs. Forward Voltage V_F

PACKAGE DIMENSIONS in millimeters (inches): **SOT-23**



Document no.: 6.541-5014.01-4
Rev. 8 - Date: 23.Sept.2009
17418



SOT-23

Orientation in carrier tape
SOT-23
S8-V-3929.01-006 (4)
04.02.2010
22607

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